TOPICAL REVIEW

W igner crystal physics in quantum wires

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A bstract. The physics of interacting quantum wires has attracted a lot of attention recently. W hen the density of electrons in the wire is very low, the strong repulsion between electrons leads to the formation of a W igner crystal. We review the rich spin and orbital properties of the W igner crystal, both in the one-dim ensional and quasi-one-dimensional regime. In the one-dimensional W igner crystal the electron spins form an antiferrom agnetic Heisenberg chain with exponentially small exchange coupling. In the presence of leads the resulting inhom ogeneity of the electron density causes a violation of spin-charge separation. As a consequence the spin degrees of freedom a ect the conductance of the wire. Upon increasing the electron density, the W igner crystal starts deviating from the strictly one-dimensional geometry, forming a zigzag structure instead. Spin interactions in this regime are dom inated by ring exchanges, and the phase diagram of the resulting zigzag spin chain has a number of unpolarized phases as well as regions of complete and partial spin polarization. F inally we address the orbital properties in the vicinity of the transition from a onedimensional to a quasi-one-dimensional state. Due to the locking between chains in the zigzag W igner crystal, only one gapless mode exists. Manifestations of W igner crystal physics at weak interactions are explored by studying the fate of the additional gapped low energy mode as a function of interaction strength.

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1. Introduction

F inst experiments [1, 2] on electronic transport in one-dimensional conductors revealed the remarkable quantization of conductance in multiples of the universal quantum $2e^2=h$, where e is the elementary charge and h is P lanck's constant. These experiments were performed by conning two-dimensional electrons in G aA sheterostructures to one dimension by applying a negative voltage to two gates, thereby forcing the electrons to

ow from one side of the sample to the other via a very narrow channel. Such devices, typically referred to as quantum point contacts, are the simplest physical realization of a one-dimensional electron system. A lthough the length of the one-dimensional region in quantum point contacts is relatively short, the quantization of conductance indicates that transport in such devices is essentially one-dimensional. Longer quantum wires have been created later using either a dimensional region ensional electrons by other means, such as in cleaved-edge-overgrow the devices [4]. Finally, a fundamentally dimension nanotubes [5, 6]. The interest in the study of one-dimensional conductors is stimulated by the relatively low disorder in these systems and by the ability to control their parameters. For instance, the empty, which can be tuned by changing the gate voltage. Thus quantum wire devices represent one of the simplest interacting electron systems in which a detailed study of transport properties can be performed.

Interactions between one-dimensional electrons are of fundamental importance. Unlike in higher-dimensional systems, in one dimension the low-energy properties of interacting electron systems are not described by Fermi-liquid theory. Instead, the so-called Tomonaga-Luttinger liquid emerges as the proper description of the system in which, instead of fermionic quasiparticles, the elementary excitations are bosons [7]. Interestingly, the quantization of conductance in quantum point contacts is well understood in the framework of noninteracting electrons [8] despite the relatively strong interactions in these devices. This paradox was resolved theoretically [9, 10, 11] by considering a Luttinger liquid with position-dependent parameters chosen in a way that models strongly interacting electrons in the quantum wire connected to leads in which interactions can be neglected. It was found that the dc conductance of such a system is completely controlled by the leads, and is therefore insensitive to the interactions.

The latter conclusion is in apparent disagreem ent with experiments observing the so-called 0.7 structure in the conductance of quantum point contacts [12, 13, 14, 15, 16, 17, 18, 19, 20]. This feature appears as a quasi-plateau of conductance at about 0:7 $2e^2$ =h at very low electron density in the wire, and usually grows with temperature. A num ber of possible explanations have been proposed, most of which attribute the feature to the fact that at low densities the electron strength is strongly enhanced. One of the most common explanations attributes the 0.7 structure to spontaneous polarization of electron spins in the wire [12, 13, 14, 15, 16, 17, 18, 20, 21, 22, 23, 24, 25]. A lthough such polarization is forbidden in one dimension [26], the electrons in quantum



Figure 1. (a) A one-dimensional W igner crystal form ed in a quantum wire at low electron density. (b) The zigzag W igner crystal form s in a certain regime of densities when the electrons are con ned to the wire by a shallow potential.

w ires are, of course, three-dimensional, albeit con ned to a channel of small width. This deviation from true one-dimensionality may, in principle, give rise to a spin-polarized ground state of the interacting electron system.

The electrons in quantum wires interact via repulsive C oulom b forces. As a result of the long-range nature of the repulsion, at low density the kinetic energy of the electrons is small compared to the interactions. To minimize their repulsion, electrons form a periodic structure called the W igner crystal [27]. In one dimension the long-range order in the W igner crystal (Figure 1 (a)) is smeared by quantum uctuations 28], and therefore the crystalline state can be viewed as the strongly-interacting regime of the Luttinger liquid. However, the presence of strong short-range order provides a clear physical picture of the strongly interacting one-dimensional system and enables one to develop a theoretical description of quantum wires in the low-density regime.

In the Wigner crystal regime the electrons are strongly con ned to the vicinity of the lattice sites. As a result the exchange of electron spins is strongly suppressed, and only the nearest neighbor spins are coupled to each other. One can then think of the electron spins form ing a Heisenberg spin chain with a coupling constant J much smaller than the Fermi energy E_F . The presence of two very dierent energy scales E_F and J for the charge and spin excitations distinguishes the strongly interacting W igner crystal regime from a generic one-dimensional electron system with moderately strong interactions. In particular, the Luttinger liquid theory is applicable to the W igner crystal only at the J. On the other hand, if any of the important energy scales of lowest energies, " the problem exceed J, the spin excitations can no longer be treated as bosons, and the conventional Tom onaga-Luttinger picture fails. One of the most interesting examples of such behavior occurs when the tem perature T is in the range J Т $E_{\rm F}$. In this case the charge excitations retain their bosonic properties consistent with Luttinger liquid theory, whereas the correlations of electron spins are completely destroyed by them al

uctuations. Such one-dimensional systems are not limited to the W igner crystal regime and are generically referred to as spin-incoherent Luttinger liquids. We argue in Sec. 2 that the coupling of spin and charge excitations in this regime leads to a reduction of the conductance of the quantum wire from $2e^2=h$ to $e^2=h$. A number of additional interesting properties of spin-incoherent Luttinger liquids are discussed in a recent review [29].

The electrons in a quantum wire are con ned to one dimension by an external potential. In the common case of the potential created by negatively charged gates placed on top of a two-dimensional electron system, the con ning potential can be

rather shallow. In this case the strong repulsion between electrons can force them to move away from the center of the wire, transforming the one-dimensional W igner crystal to a quasi-one-dimensional zigzag structure, Figure 1 (b). In the case of classical electrons such a transition has been studied in [30, 31, 32]; we review this theory in Sec. 3. The zigzag W igner crystal has rich spin properties due to the fact that each electron can now be surrounded by four neighbors with signi cant spin coupling. R ing exchange processes play an important role and m ay under certain circum stances give rise to a spontaneous polarization of electron spins. The spin properties of the zigzag W igner crystals are discussed in Sec. 4.

The transform ation of a one-dimensional W igner crystal to the zigzag shape is a special case of a transition from a one-dimensional to a quasi-one dimensional state of electrons in a quantum wire. A nother such transition occurs in the case of non interacting electrons when the density is increased until population of the second subband of electronic states in the con ning potential begins. These two transitions seem to have rather di erent properties. Indeed, in the case of non interacting electrons the population of the second subband entails the emergence of a second acoustic excitation branch in the system. On the other hand, even though the zigzag crystal has two rows, their relative motion is locked, and one expects to nd only one acoustic branch in this case. It is therefore interesting to explore how the number of acoustic excitation branches changes as the interaction strength is tuned. In the regime of strong interactions this requires developing the quantum theory of the transition from a one-dimensional to a ziqzaq W igner crystal. W e discuss such a theory in Sec. 5, where it is shown that uctuations do not lead to the emergence of a second acoustic branch in the quantum zigzag crystal. This feature of the W igner crystal survives even at weak interactions, with the second acoustic branch appearing only when the interactions are completely tumed o .

2.0 ne-dim ensional crystal

2.1. Quantum wire at low electron density

Electrons in a quantum wire repel each other with C oulomb forces. To characterize the strength of interactions, let us compare the typical kinetic energy of an electron, which is of the order of the Ferm i energy $E_F = 2n^2 = m$, with the typical interaction energy $e^2n = .$ (Here n is the electron density, m is the electric mass, and is the dielectric constant of the medium.) C learly, the C oulomb repulsion dominates over the kinetic energy in the low-density regime $na_B = n^2 = m\hat{e}$ is the B ohr's radius in the material. Then the ground state of the system is achieved by placing electrons at well-de ned points in the wire, separated from each other by the distance n^{-1} , F igure 1(a), thus creating a W igner crystal. Because the kinetic energy of electrons is small, the amplitude x of the zero-point uctuations of electrons near the sites of the W igner lattice is much smaller than the period of the crystal, n x $(ng)^{1=4}$ 1. In experiment the quantum wire is usually surrounded by metal gates. As a result, the Coulomb interactions between electrons are screened at large distances by image charges in the gates. For example, if the gate is modeled by a metal plane at distance d from the wire, the interaction potential becomes

$$V(x) = \frac{e^2}{x^2} \frac{1}{x^2 + (2d)^2} :$$
 (1)

At large distances this potential falls o as V (x) $2^2 d^2 = jx^3$, much more rapidly than the original C oulom b repulsion. As a result, in the limit n ! 0 the crystalline ordering of electrons will be destroyed by quantum uctuations. C on parison of the Ferm ienergy with the screened C oulom b repulsion (1) shows that the W igner crystal exists in the range of densities $a_B d^2$ n a_B^{-1} , provided that the distance to the gate d a_B . In typical experiments with G aAs quantum wire devices $a_B = 10$ nm and d & 100nm; thus the W igner crystal state should persist until unrealistically low densities 10^3 nm⁻¹.

Sim ilar to phonons in conventional crystals, the W igner crystal supports acoustic plasm on excitations | propagating waves of electron density. The speed of plasm ons is given byz

$$s = \frac{r}{\frac{2e^2n}{m}\ln(8.0nd)}$$
 (2)

The H am iltonian describing these low energy excitations is easily obtained by treating the W igner crystal as a continuous medium . Adding the kinetic energy and the potential energy of elastic deformation, one obtains

$$H = \frac{p^2}{2mn} + \frac{1}{2}mns^2 (\theta_x u)^2 dx; \qquad (3)$$

where u(x) is the displacement of the medium at point x from its equilibrium position, and p(x) is the momentum density. In one dimension the acoustic excitations destroy the long range order in the crystal even at zero temperature, $h[u(x) = u(0)^{\frac{3}{2}}i'$ (~= mns) $\ln nx x$

In the model of spinless electrons, H am iltonian (3) accounts for all possible low – energy excitations of the system . However, in the presence of spins, there are additional excitations not included in (3). In the W igner crystal regime the electrons are localized near their lattice sites, Figure 1(a), and to a rst approximation the spins at di erent sites are not coupled. The exchange coupling of two spins at neighboring sites occurs via the process of two electrons switching their places on the W igner lattice. W hen the electrons approach each other, the strong C oulom b repulsion creates a high potential barrier. As a result, the exchange processes are very weak, and only the coupling of the

z The result (2) was derived in [33] for densities in the range d¹ n a_B^{-1} . Extending their calculation to the density range $a_B = d^2$ n d¹, one nds $s = [24e^2n^3d^2 (3) = m\frac{1}{2}]^{-2}$. x In the absence of the screening gate the plasm on speed s diverges at small wavevectors, see (2) at d! 1. A lthough this e ect suppresses the quantum uctuations, it is not su cient to restore the long-range order [28]. nearest neighbor spins needs to be taken into account. The H am iltonian describing the spin excitations takes the form

$$H = \int_{1}^{\Lambda} J S_{1} \qquad S_{1}; \qquad (4)$$

where S_1 is the spin at site 1. As the exchange processes involve tunneling through a high barrier, the exchange constant is exponentially suppressed [34, 35, 36],

$$J / \exp \frac{p_{\overline{na_B}}}{na_B}$$
; (5)

where 2:80 §0, 51, 52], see also Sec. 4.1.1. Taken together, equations (3) and (4) account for all low-energy excitations of the one-dimensional W igner crystal, i.e., the Ham iltonian of the system can be represented as the sum

$$H = H + H : (6)$$

Because of the absence of long-range order, one expects that in the low-energy lim it the W igner crystal should be a special case of the Luttinger liquid. The latter is commonly described [7] by a Ham iltonian of the form (6), with the charge and spin Ham iltonians, H and H , given by

$$H = \frac{\sim u}{Z} \frac{^{2}K}{^{2}} + K^{1} (\theta_{x})^{2} dx;$$
(7)

$$H = \frac{\sim u}{2} {}^{2}K {}^{2} + K {}^{1} (@_{x} {})^{2} dx + \frac{2g_{12}}{(2)^{2}} \cos^{2} \frac{g_{12}}{8} (x) dx; (8)$$

Here the bosonic elds ; and ; describe the charge () and spin () excitations propagating with velocities u_i . They obey canonical commutation relations $[(x); \circ(y)] = i \circ (x \quad y)$. In the case of repulsive interactions, the Luttinger liquid parameter K is in the range 0 < K < 1. The cosine term in (8) is marginally irrelevant, i.e., the coupling constant g_{12} scales to zero logarithm ically at low energies. At the same time, the parameter K approaches unity as $K = 1 + g_{12} = 2 u$.

Both H am iltonians (3) and (7) describe propagation of elastic waves in the medium . Their form all equivalence is established [36] by identifying

$$(x) = \frac{n}{2}u(x);$$
 $(x) = \frac{\frac{p}{2}}{n^{2}}p(x);$ $u = s;$ $K = \frac{n}{2ms};$ (9)

On the other hand, even though both H am iltonians (4) and (8) describe spin excitations in the system, their equivalence is not obvious. Indeed, H am iltonian (4) is expressed in terms of spin operators S_1 of the electrons, whereas its Luttinger-liquid analog (8) is expressed in terms of the bosonic elds and . The connection is established via the well-known procedure [7] of bosonization of the H eisenberg spin chain (4). This procedure is applicable at energies much smaller than the exchange constant J, and reduces H am iltonian (4) to the form (8), see R ef. [36]. One therefore concludes that at low energies the W igner crystal can indeed be viewed as a Luttinger liquid.

It is important to point out, however, that the equivalence of the W igner crystal and Luttinger liquid holds only at very low energies, "J. Given the exponential

dependence (5) of the exchange constant on density, one can easily achieve a regime when an important energy scale, such as the temperature, is larger than J. In this case the bosonization procedure leading to (8) is inapplicable, and the form (4) should be used instead. On the other hand, as long as temperature and other relevant energy scales are sm aller than the Ferm i energy, the charge excitations are bosonic and adequately described by either Ham iltonian (3) or (7).

2.2. Spin-charge separation in the one-dimensional Wigner crystal

The Ham iltonian (6)-(8) of the Luttinger liquid consists of two separate commuting contributions associated with the charge and spin degrees of freedom. Consequently, the low-energy excitations of the system are charge and spin waves, decoupled from each other, and propagating at di erent velocities u and u. The operator annihilating a (right-m oving) electron with spin in this theory has the form

$$_{R}(x) = \frac{e^{ik_{F}x}}{2} \exp \frac{i}{2}[(x) (x)] \exp \frac{i}{2}[(x) (x)]; (10)$$

in which the charge and spin contributions explicitly factorize. (Here is a shortdistance cuto , $k_F = n=2$ is the Ferm i wavevector of the electrons, and the + = sign corresponds to electron spin = ";#.)

The Hamiltonian of the W igner crystal (6) also consists of two commuting contributions describing the charge and spin degrees of freedom, with the main di erence being the di erent form (4) of H. However, the analogy with the Luttinger liquid is not complete, as the electron annihilation operator no longer factorizes [37, 38],

$$_{R} (x) = \frac{e^{i2k_{F}x}}{2} \exp \frac{i}{2} [2 (x) (x)] Z_{1}; \qquad (11)$$

Here the operator Z₁; acts upon any state of the spin chain (4) and produces a state with one less spin by removing spin at site number 1. The form of the ferm ion operator (11) relects the fact that when an electron is removed from the W igner crystal, one of the sites of the spin chain (4) is also removed. In the absence of plasm on excitations, the sites are equidistant, and the site at point x has the number 1 = nx. On the other hand, if plasm ons propagate though the crystal, the electrons shift by a distance proportional to , and the spin is removed from the site $1 = nx + \frac{p_2}{2}$ (x), see (11). Thus the absence of factorization of the charge and spin components of the ferm ion operator (11) relects the simple fact that the spins S₁ in the spin chain (4) are attached to the electrons.

The absence of spin-charge separation in the Ham iltonian of the W igner crystal manifests itself if the system is not uniform, such as in the case of a quantum wire with a low electron density that depends on position, n = n(x). A ssum ing that the variations of n(x) occur at a length scale much larger than the distance between electrons, one can still bosonize the charge modes near every point in space, while accounting for the x-dependence of the parameters u and K. Thus one obtains

$$H = \frac{-u(x)}{2} - \frac{2}{K} (x)^{2} + [K(x)]^{1} (\theta_{x})^{2} dx: \qquad (12)$$



F igure 2. A quantum wire form ed by applying negative voltage to the gates placed on top of a two-dimensional electron system. Electrons in the narrow channel between the gates are one-dimensional and their density is su ciently low to achieve the W igner crystal regime. Away from the center of the wire the electron density increases, and even the short range ordering of electrons is destroyed by quantum uctuations.

The exchange constant J in the Ham iltonian (4) of the spin chain also acquires an x-dependence, as it clearly depends on the electron density, see (5). Thus the spin Ham iltonian takes the form

$$H = \int_{1}^{X} J \, 1 \, \frac{p_{\overline{2}}}{2} \quad (x_1) \, S_1 \quad S_1; \qquad (13)$$

where x_1 is the initial position of the 1-th electron. The appearance of the charge eld

in H again accounts for the fact that the plasmons shift the site l of the spin chain from its initial position by $\frac{P}{2}$. Therefore the two contributions H and H to the H am iltonian of the W igner crystal commute only in the uniform system, when the exchange constant J does not depend on position.

2.3. Conductance of a W igner-crystal wire

In experiment, the quantum wires are usually made by conning a two-dimensional electron system to a one-dimensional channel. One of the most common techniques is to place two metal electrodes above a G aA sheterostructure in which a two-dimensional electron system is formed, Figure 2. When a negative voltage is applied to the gates, the resulting electrostatic potential repels the electrons from the regions covered by the gates, but a narrow channel of electrons between the gates may still remain. The resulting quantum wire connects two large regions of two-dimensional electrons, which play the role of contacts to the wire. If the gate voltage V_g is properly tuned, the electron density in the center of the wire can be su ciently low for a W igner crystal to form. On the other hand, the gates do not a lect the electron density and the nature of the electron liquid in the two-dimensional leads.

The physics of interacting electrons in two or three dimensions is very di erent from that of one-dimensional system s. Although at extremely low densities the electrons will form a W igner crystal, this does not happen in typical G aAs heterostructures. Instead, the electrons are believed to be in a conventional Ferm i-liquid state with quasiparticle excitations obeying Ferm i statistics and carrying the charge of a single electron. In a one-dimensional system such a situation may only occur in the absence of interactions, as otherwise a Luttinger liquid state with bosonic excitations is formed. In the absence of interactions, however, the Ferm i-liquid and Luttinger-liquid pictures are equivalent. Thus it is convenient to model the quantum wire device by a one-dimensional model with position-dependent interactions and electron density. In the central part of the system the density is small so that the interactions may be electively strong. This region models the quantum wire. As one moves away from the central region, the density grows, the interactions become small, and asymptotically at large distances the electrons become noninteracting. These two sem i-in nite noninteracting regions model the two-dimensional leads.

Such a model was used in [9, 10, 11] to calculate the conductance of a quantum wire described by the Luttinger liquid model. The Ham iltonian studied was essentially identical to (12), as the electrons were assumed to be spinless and only charge modes needed to be accounted for. It was demonstrated that the dc conductance of the wire is not a ected by the interactions and remains quantized at $\hat{e}=h$. Let us illustrate this result with a simple sem iclassical calculation.

We start with the hom ogeneous wire, and for sim plicity, instead of the H am iltonian (7) we will use the equivalent form (3). Unlike papers [9, 10, 11], where a term was added to the H am iltonian in order to describe the bias voltage applied to the wire at point x = 0, we consider a setup in which the wire is connected to a current source. A sm all ac current with frequency ! can be represented in terms of the velocity <u>u</u> of the elastic medium and the electron density as

$$n\underline{u}\underline{j}_{k=0} = I_0 \cos ! t$$
(14)

This expression should be viewed as a time-dependent boundary condition imposed on the elastic medium. As a result the medium begins to move periodically with frequency !, and plasmons propagating into the in nite leads dissipate power W = fR=2 from the current source, where R is the resistance of the system. Let us calculate W in terms of the parameters of the elastic medium. Since the plasmons carry the energy of the oscillating medium in two directions at speed s, we can express the dissipated power as

$$W = 2shEi;$$
(15)

where hE i is the energy density of the system. The latter consists of two contributions, the kinetic and potential energies represented by the two terms in (3). In a harm onic system the time-averaged values of the kinetic and potential energies are equal, so we will evaluate hE i by doubling the kinetic energy,

$$hEi = m n \underline{u}^{2} = \frac{m}{e^{2}n} I_{0}^{2} h\cos^{2}! ti = \frac{m}{2e^{2}n} I_{0}^{2};$$
(16)

where we expressed the velocity <u>u</u> in terms of the current using (14). Substituting this expression into (15) and comparing the result with the Joule heat law $W = I_0^2 R = 2$, we

nd the resistance

$$R = \frac{2m s}{e^2 n} = \frac{h}{e^2} \frac{s}{v_F};$$
(17)

where we used the density $n=k_F=$ for spinless electrons and de ned the Ferm ivelocity in the interacting system as $v_F=\sim k_F=m$.

In the noninteracting limit, where the Luttinger liquid theory reproduces the low – energy properties of the Ferm i gas, the plasm on velocity $s = v_F$, and we recover the well-known result $R = h=e^2$. The model considered in [9, 10, 11] was described by the H am iltonian (12) of the inhom ogeneous Luttinger liquid, where the interactions are present only in a region of nite size L, modeling the wire, and vanish at $x ! 1 \cdot It$ is easy to see that the above calculation of the resistance is applicable to such a system as long as the low-frequency limit is considered. Indeed, at ! ! 0 the wavelength of the plasm ons s=! is much larger than L, so the emission of the plasm ons occurs in the noninteracting leads. Thus we have recovered the result [9, 10, 11] for the conductance, $G = e^2 = h$.

O ur simple calculation also enables us to interpret the absence of corrections to the conductance due to electron-electron interactions in a nite region of a one-dimensional system. In the Luttinger liquid theory the main e ect of the interactions is to change the compressibility of the electron system, thereby a ecting the second term in β). In the dc limit the wavelength of the plasm ons is in nitely large, and thus the deform ation $\theta_x u$ within the nite-size interacting region is negligible. Thus the system behaves as a noninteracting one.

The above result for the spinless Luttinger liquid can be easily generalized to the case of electrons with spin. As we discussed in Sec. 2.2, within the Luttinger-liquid approximation the charge and spin degrees of freedom are not coupled. Thus the applied bias or electric current couples only to the charge modes, and the above discussion can be repeated with the only modication being the dimension n = 2k = between the density and the Ferm is avevector. Substituting this expression instead of $n = k_F = in$ (17) we not the resistance of the charge modes

$$R = \frac{h}{2e^2};$$
(18)

and thus the expected doubling of the conductance, $G = 2e^2 = h$.

On the other hand, we saw in Sec. 2.2 that in the inhom ogeneous W igner crystal there is no spin-charge separation, i.e., the Ham iltonian (13) of the spin excitations depends explicitly on the charge eld . One can therefore expect that the spin degrees of freedom will a ect conductance when the W igner crystal is not equivalent to the Luttinger liquid. Indeed, we show below that the spins have a signi cant e ect on the electronic transport at tem peratures T & J.

In treating a one-dimensional W igner crystal attached to noninteracting leads one has to overcome a fundamental problem caused by the lack of quantitative theory for the crossover regions that connect them, Figure 2. In the case of spinless electrons both the W igner crystal and the leads can be viewed as special cases of the Luttinger

liquid, assuming that one is only interested in the low-energy properties of the system. Thus one can use the model (12) of the inhom ogeneous Luttinger liquid and obtain reliable results, provided that the exact form of the x-dependences of the parameters is not important. In the presence of spins there is an additional complication caused by the fact that the spin sector of a W igner crystal is described by the Ham iltonian of a Heisenberg spin chain (4) because the spins are attached to well-localized electrons. Such a description is appropriate in neither the crossover region nor the leads, where the short-range crystalline order is absent. In our further discussion we will nevertheless use the model of the inhom ogeneous spin chain (13) for the whole system. This model is justied if the temperature is small compared to the Fermi energy in the center of the wire. W hen one moves away from the center, the density n grows, and consequently the exchange constant J rapidly grows, see (5). Even if in the center of the system we had T, the crossover regim e J T willoccurwhile the wire is still in the W igner crystal J regime, as J is still sm all compared to E_F. Eventually, when one moves su ciently far from the center of the wire the exchange J becomes of order $E_{\rm F}$, and the spin chain model is no longer appropriate. However, since in those regions we have J T, the Heisenberg model (4) is equivalent to the spin sector (8) of the Luttinger liquid theory appropriate for both the crossover regions and the leads. Thus, at T $E_{\rm F}$, one can describe the spin properties of the system by the model (13) of an inhom ogeneous spin chain as long as the exact shape of the dependence J (1) does not a ect the results.

Form ally the quantum wire will be described by the Ham iltonian H + H given by (12) and (13). The electron density has a minimum at the center of the wire, resulting in an exponentially sm all exchange constant J, Figure 3. Far from the center of the wire the exchange constant reaches the value J_1 $E_{\rm F}$. Since J depends on position, the spin excitations are coupled to the charge excitations. To d the resulting correction to the conductance of the wire, it is convenient to consider the setup of xed current through the wire. Given the standard bosonization relation between Q_x and the electron xing the current I at point x = 0 one in poses the boundary condition density, by $(\frac{1}{2})q(t)$ on the charge modes, where q(t) is the charge transferred (0;t) =through the wire, i.e., I = eq. As discussed above, at small frequencies ! the plasm on wavelength is very large, and electrons move in phase over distances much longer that the length of the wire. One can therefore replace (x) by its value at x = 0 everywhere within the range where J depends on position, and convert the Ham iltonian (13) to the form

$$H = \int_{1}^{X} J[I+q(t)]S_{1} \quad S_{1}:$$
(19)

The advantage of this form of H is that it now commutes with H. This does not mean that spin-charge separation is restored, as the spin excitations are still a ected by the electric current.

An immediate consequence of the commutativity of H and H is that the application of electric current through the wire gives rise to independent excitation of the charge and spin modes. A sum ing that the power dissipated in each channel is



F igure 3. (a) The electron density as a function of position has a minimum in the center of the wire (x = 0), where na_B 1 and the W igner crystal is form ed. In the lead regions, na_B is assumed to be large such that the interactions can be neglected. (b) The low density in the wire results in the exponential suppression (5) of the exchange constant J. In the lead regions J (1) saturates at $J_1 = E_F$.

quadratic in current, we conclude W $f_R^2 = I_0^2 (R + R) = 2$. Thus the resistance of the wire is a sum,

$$R = R + R ; (20)$$

of two independent contributions due to the charge and spin excitations. Since we have already discussed the contribution (18) of the charge excitations, we now turn our attention to R $\,$.

The spin contribution to the resistance depends crucially on whether the tem perature is small or large compared to the value J of the exchange constant in the center of the wire, see Figure 3. At T J one can bosonize the spin excitations, i.e., convert H to the form (8) with position-dependent parameters. W ithin this approach, an attempt to account for the coupling to the charge modes in (13) would result in corrections cubic in the bosonic elds. Such corrections are irrelevant perturbations, which are usually neglected as their contribution vanishes at T ! 0. Thus one concludes that R = 0 in the lim it T=J ! 0.

The absence of dissipation in the spin channel at low tem perature can be interpreted as follows. The low-energy excitations of a Heisenberg spin chain are the so-called spinons [39] with spectrum

$$\mathbf{''}(\mathbf{k}) = \frac{J}{2} \sin \mathbf{k}; \tag{21}$$

where the wavevector k is de ned in the interval (0;). At low temperature the state of the spin chain can be viewed as a dilute gas of spinons. Let us consider propagation of spinons in the spin chain (19) with non-uniform J, Figure 3(b), assuming for the moment q(t) = 0. If the variation of J(l) is very gradual, one can use the spectrum (21) with 1-dependent exchange J. As a spinon propagates through the wire, its energy is conserved, but its momentum and velocity change because of the variation of J along the system. Clearly, if the energy of a spinon is less than J=2, where J is the smallest value of the exchange constant in the system, Figure 3(b), it passes through the wire without scattering. Conversely, spinons with energies exceeding J=2 are backscattered, Figure 4.



F igure 4. Scattering of spinons at the quantum wire. Spinons with energies below J=2 (shown in blue) slow down in the wire, but continue to move forward to the opposite lead. Spinons with energies above J=2 (shown in red) stop before they reach the center of the wire and are scattered back.

At q(t) \leq 0 the dependence J(1) shown in Figure 3(b) is not static, but rather oscillates in position with respect to the spin chain. (M ore physically, the ac current m oves the W igner crystal with respect to the quantum wire, causing the time dependence of the exchange constants in (19).) The spinons passing through the wire without scattering are not a ected by this oscillation. On the other hand, the spinons with energies " > J=2 are re ected by a moving scatterer. Such processes do change the energy of the spinons, and eventually lead to dissipation. At low temperature T J the density of such (therm ally-activated) spinons is very low, and one expects only an exponentially sm all resistance in this regime,

$$R / exp = \frac{J}{2T}$$
; T J: (22)

It is worth m entioning that the resistance (22) is caused by excitations with energies of the order of the spinon bandwidth J. Such a correction cannot in principle be obtained by the bosonization procedure, which is accurate only at energies much smaller than J.

The expression (22) in plies that the resistance R grows with temperature. At J one expects this growth to saturate. Indeed, in this limit one can assume that J = 0 in the center of the wire, i.e., the propagation of spin excitations through the wire is no longer possible. On the other hand, in the leads one still has T $J_1 = E_F$, and the picture of a dilute spinon gas still applies. Every spinon moving toward the wire is rejected back, resulting in a nite dissipation that no longer depends on J.

Unfortunately, one cannot easily develop the theory of scattering of spinons in this regime, as such processes occur in the region where J(l) = T, and the spinon gas is no longer dilute. One can, however, conjecture that the dissipation resulting from all the spin excitations being relected by the wire is universal in the sense that it does not depend on the exact nature of the scatterer. Thus if one can solve another problem where all the spin excitations in a one-dimensional system are relected by a moving scatterer, the result for R should be the same. The simplest example of such a problem is obtained in the same W igner-crystal setup in the presence of a magnetic eld B su cient to polarize electrons in the center of the wire, $T; J = B = E_F$, where B is the Bohr magneton. Then only the electrons with spin directed along the eld propagate through the wire whereas the electrons with opposite spin are con ned

to the leads. This problem can be easily solved in the fram ework of the bosonization approach [36], resulting in

$$R = \frac{h}{2e^2}; \qquad T \qquad J:$$
(23)

The result is easily understood by noticing that in combination with (20) and (18) one

nds the conductance $G = \hat{e} = h$ which is the expected result for the conductance of a spin-polarized wire, where only one type of charge carriers participates in conduction. By our conjecture, the same reduction of conductance from $2e^2 = h$ to $e^2 = h$ occurs in the absence of the eld, provided J T, because in both cases all the spin excitations are relevened by the wire, resulting in the same dissipation. This conclusion is consistent with some of the measurements of the conductance of quantum wires a low density [14, 15, 17, 18], showing a small plateau at $G = e^2 = h$.

3. C lassical transition to the zigzag structure

In section 2, we discussed the physics of a purely one-dimensional crystal. Experimentally, however, quantum wires are created by con ning three-dimensional electrons to a narrow channel by an external con ning potential. The electron system in the wire can be viewed as one-dimensional as long as the typical energy of the transverse motion is large compared with all other important energy scales; otherwise, deviations from one-dimensionality arise. The remainder of this review addresses the resulting quasi-one-dimensional physics, starting with the classical transition from a one-dimensional to a quasi-one-dimensional W igner crystal that was studied in Refs. [30, 31, 32].

To be specific, we consider here a coning potential that minics the experimental situation. In a typical setup the coning potential in one direction, say the z-direction, is provided by the band bending at the interface of two semiconductors with dimensional structure (typically G aA s and A IG aA s). This provides a very tight coning nement and, correspondingly, the energy scales for transverse excitations are large. Therefore, at low energies, the possibility of electron motion in the z-direction may be neglected. By contrast, coning nement in the y-direction is provided by nearby metallic gates which create a relatively shallow coning potential. Deviations from one-dimensionality arise due to lateral displacements in this shallow potential which may be assumed parabolic:

$$V_{conf} = \frac{1}{2}m^{2} y_{i}^{2};$$
 (24)

where is the frequency of harm onic oscillations in the con ning potential, and y is the transverse coordinate of the electron at site i.

As the electron density n grows, so does the typical energy V_{int} (\hat{e} =)n of the C oulomb interaction between electrons. Eventually, it becomes energetically favorable for electrons to move away from the axis of the wire. This happens when the distance

between particles is of the order of the length scale

$$r_{0} = \frac{1}{m^{2}} \frac{2e^{2}}{m^{2}};$$
 (25)

de ned by the condition that the con nem ent and the Coulomb repulsion, $y_{onf}(r_0) = \frac{1}{2}m - r_0^2$ and $V_{int}(r_0) = e^2 = r_0$, are equal [32].

The quasi-one-dimensional arrangement that maximizes the distance between electrons and consequently minimizes the Coulomb interaction energy $V_{int} = (e^2 =)_{i < j} jr_i r_j j^1$ at a given cost of conning potential energy is a zigzag structure, see Figure 1 (b). The exact shape of the zigzag crystal can be found by minimizing its energy per particle

$$E = \frac{e^2}{r_0} \cdot \frac{x^1}{2} \cdot \frac{w^2}{1} = \frac{1}{1} \cdot \frac{1}{1} + \frac{1}{(1 - \frac{1}{2})^2 + \frac{2w^2}{4r_0^2}} \cdot \frac{1}{4r_0^2} + \frac{w^2}{4r_0^2};$$
(26)

with respect to the distance w between the two rows of the zigzag crystal. Here $= nr_0$ is the dimensionless density, the rst two terms account for the interactions between electrons within the same row and in di erent rows of the zigzag structure, respectively, and the last term stems from the con ning potential.

0 ne nds that the distance between rows is given by the solution of the equation 1

$$B_{0}^{3} \frac{3}{4} \frac{1}{1 + 1} \frac{1}{(1 - \frac{1}{2})^{2} + \frac{2w^{2}}{4r_{0}^{2}}} \qquad B_{1}^{C} w = 0:$$
(27)

Below the critical density [30, 31]

$$_{c} = \frac{3}{7} \frac{4}{(3)} = 0.780;$$
 (28)

the only solution is w = 0 and, therefore, the crystal is one-dimensional. At densities,

> c, a lower-energy solution with w \notin 0 appears, and the zigzag structure is form ed. The distance between the two rows of the zigzag crystal grows with density. In particular, just above the transition point c, the distance between rows behaves as $w = r_0 \begin{bmatrix} 24=93 & (5) = c \end{bmatrix}^2$, where = c. Upon further increasing the density, the zigzag crystal eventually becomes unstable at 1:75. At larger densities, > 1:75, structures with m ore than two rows are energetically favorable [32].

Such a classical description of the system is valid only in the limit where the distance between electrons is much larger than the Bohr's radius, n¹ a_B . A sthe zigzag regime corresponds to distances between electrons of order r_0 , it can only be achieved if r_0 is su ciently large, r_0 a_B . This motivates the introduction of a density-independent parameter

$$\mathbf{r} = \frac{\mathbf{r}_0}{\mathbf{a}_{\mathrm{B}}}; \tag{29}$$

which characterizes the strength of C ould be interactions with respect to the conning potential. If r 1, as the electron density grows, the interactions become weak at

n a_B^1 r_0^{-1} . As a result, the one-dimensional W igner crystal melts by quantum uctuations before the zigzag regime is reached. By contrast, if r 1, interactions are still strong (na_B 1) at densities n r_0^1 , and the classical description of the transition to the zigzag regime is applicable. As r / $2^{=3}$, the strongly interacting case therefore requires a shallow con ning potential. Note that the condition r 1 can be rewritten as W a_B , where $W = \frac{P}{\sqrt{-m}}$ is the (quantum) width of the wire.

4. Spin properties of zigzag W igner crystals

In a W igner crystal electrons are localized near their lattice positions due to the mutual C oulom b repulsion. The potential landscape thus created is such that any deviation from these lattice positions incurs an increase in C oulom b energy. In particular, the exchange processes which give rise to spin-spin interactions require tunneling of electrons through the C oulom b barrier that separates them . As pointed out in section 2.1, the resulting spin couplings in a one-dimensional crystal are fairly simple: as the tunneling am plitude decays exponentially with distance, only nearest neighbor exchange processes have to be taken into account. Thus, the spin degrees of freedom of a one-dimensional W igner crystal are described by an antiferrom agnetic H eisenberg chain (4) with nearest neighbor exchange energy J whose properties were discussed in section 2.

In a zigzag chain, spin couplings become more interesting. Close to the zigzag transition, the nearest neighbor exchange is dom inant as in the one-dimensional case. However, as the zigzag structure becomes more pronounced each electron is surrounded by four close neighbors rather than only two as in the one-dimensional crystal, and, therefore, the next-nearest neighbor couplings can no longer be neglected. Instead of one coupling constant, one needs to take into account a nearest neighbor exchange constant J_1 and a next-nearest neighbor exchange constant J_2 . Both couplings are antiferrom agnetic and, therefore, compete with each other. If J_2 is large enough (J₂ & 0:24::J₁ [40, 41, 42]), the antiferrom agnetic ground state gives way to a dimer phase characterized by a non-vanishing order parameter D / $h(S_{2i+1})$ S_{2i1}) Si and a resulting spin gap. The dimer structure is particularly simple on the so-called M a jum dar-G hosh [43, 44] line $J_2 = 0.5J_1$, where the dimers are just nearest neighbor singlets. The magnitude of the spin gap is a non-monotonic function of the ratio $J_2=J_1$: it reaches its maximum close to the Majum dar-Ghosh line and becomes exponentially $\mathfrak{s}\mathfrak{m}$ all at J_2 J_1 .

It turns out, how ever, that these two-particle exchanges are not su cient to describe the spin physics of the zigzag crystal. In addition, ring exchanges, i.e., cyclic exchanges of n 3 particles, have to be taken into account. De ning exchange constants in such a way that they are all positive, the Ham iltonian of the system then reads

$$H_{ring} = \frac{1}{2} \int_{1}^{X} J_{1}P_{1 \neq 1} + J_{2}P_{1 \neq 2} \quad J_{3} (P_{1 \neq 1 \neq 2} + P_{\neq 2 \neq 11}) + J_{4} (P_{1 \neq 1 \neq 3 \neq 2} + P_{\neq 2 \neq 3 \neq 11}) \quad :::;$$
(30)

where P_{ik} is a permutation operator and $P_{i_1 :::i_N} = P_{i_1 i_2} P_{i_2 i_3} :::P_{i_N i_1}$. Here we still label particles according to their position along the wire axis only: thus, nearest neighbors are particles in opposite rows whereas next-nearest neighbors are the closest particles within the same row. Note that for densities in the range 1:45 < < 1:75 the lateral displacement w is so large that the distance between nearest neighbors becomes larger than the distance between next-nearest neighbors.

R ing exchanges are interesting because they m ight stabilize a ferrom agnetic ground state. W hile exchanges involving even numbers of particles favor a spin-zero ground state, exchanges involving odd numbers of particles favor a ferrom agnetic arrangem ent of spins [45]. Thus, the simplest ring exchange process that could lead to a polarized ground state is the three-particle exchange. In fact, ring exchanges have been extensively studied in two-dimensional W igner crystals [46, 47, 48, 49]. In that case the three-particle ring exchange dom inates in the low-density limit which im plies a ferrom agnetic ground state of the strongly interacting W igner crystal is sim ilar, one needs to com pute the exchange constants for nearest neighbor, next-nearest neighbor, and the various ring exchanges.

4.1. Computation of exchange constants

To introduce the method, we start by discussing the one-dimensional case where the only non-negligible exchange is the nearest neighbor exchange.

4.1.1. Exchange constants for the one-dimensional W igner crystal The nearest neighbor exchange constant J can be determined by computing the tunneling probability of two electrons through the C oulomb barrier that separates them. If the barrier is su ciently high and, therefore, tunneling is weak, one may use the semiclassical instanton approximation. This corresponds to noting the classical exchange path in the inverted potential by minimizing the imaginary-time action.

It is convenient to rewrite the action in dimensionless form by rescaling length in units of 1=n and time in units of $m = e^{n^3}$. The action of the system is then given as

$$S_{1D} = \frac{\sim}{p - na_{B}} _{1D}; \text{ where } _{1D} [fx_{j}()g] = \begin{array}{c} Z \\ d \\ j \end{array} \xrightarrow{X} \frac{x_{j}^{2}}{2} + \begin{array}{c} X \\ \frac{x_{j}^{2}}{2} + \begin{array}{c} X \\ \frac{x_{j}}{2} + \begin{array}{c} 1 \\ \frac{x_{j}}{2} + \end{array} \end{array} \right)$$

As a stapproximation one may x the positions of all particles except the two that participate in the exchange process, say j = 1 and j = 2. Symmetry xes the center of mass coordinate of the exchanging electrons and, therefore, the minimization has to be done only with respect to the relative coordinate $x = x_2$ x_1 . The tunneling lifts the ground state degeneracy present due to inversion symmetry $x ! x_1$, and the exchange energy can be identified with the resulting level splitting.

k The ferrom agnetic state is predicted to occur only at extrem ely low densities characterized by a value of $r_s > 175$ [49], where r_s is the ratio of the C oulom b interaction energy to the Fermi energy.



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Figure 5. Sketch of typical exchange paths for (a) $_{\rm c}$ and (b) $_{\rm c}$. the size of the loop where electrons move away from the axis of the wire is determined by the length scale r_0 .

The instanton approximation yields the exchange constant J in the form (5), where is the dimensionless classical action obtained from the minimization procedure. One nds 2.81750]. At low densities, na_B 1, the exponent is large leading to exponential suppression of J, and thus the prefactor om itted in (5) is of secondary importance.

Fixing the positions of all particles except the two participating in the exchange process is a somewhat crude approximation. Neighboring electrons see a modil ed potential due the motion of the exchanging particles and, therefore, experience a force that displaces them from their equilibrium positions. A better estimate for can be obtained by including these mobile \spectator" particles in the minimization. By allowing spectators to move during the exchange process, one expects to india reduced value for because more variables are varied in the minimization procedure. It turns out, however, that the electric story small. A smore spectators are added, approaches the asymptotic value 2:798 §0, 51, 52], i.e., the result changes by less than 1%.

4.1.2. Exchange constants for the zigzag W igner crystal In the presence of a con ning potential, the motion of the exchanging electrons is no longer restricted to one dimension, i.e., the position of an electron is now given by a two-dimensional vector $r_i = (x_i; y_i)$. In particular, if the wire width W is larger than the Bohr's radius a_B or, equivalently, the interaction parameter introduced in Eq. (29) is large, r 1, electrons can m ake use of the transverse direction to go \around" rather than \through" each other during the exchange process. This reduces the Coulomb barrier and, therefore, increases the tunneling probability. The characteristic length scale of the transverse displacement is given by the length r_0 , introduced in section 3. Typical trajectories for the onedim ensional crystal are shown in Figure 5 for low and moderate densities, _c and . , respectively. At low densities, $_{\rm c}$, the exchange part follows the bottom of the con ning potential until electrons com e within a distance of order ; of each other. Thus, only a small part of the exchange path explores the transverse direction, leading to a relatively sm all correction to the tunneling action S_{1D} . The results of section 4.1.1 are recovered in the limit ! 0. A sone approaches the transition to the zigzag crystal, the exchange trajectories become more and more two-dimensional and consequently the exchange couplings are modiled signil cantly. Finally, at $>_{c}$, also the equilibrium positions of the particles are displaced in the y-direction.

The exchange constants for the zigzag W igner crystal can be obtained in the same way as for the one-dimensional W igner crystal [53]. However, by contrast to the one-

dimensional case, the structure of the zigzag crystal changes as a function of density. As a consequence the rescaling of lengths and times used in the one-dimensional case is not appropriate here. A dimensionless action in a transverse con ming potential is conveniently de med using the interaction parameter r.Namely

$$S_{2D} = \sim^{p} \frac{r}{r} _{2D}; \text{ where } _{2D} [fr_{j}()g] = \begin{array}{c} Z & X & \frac{r_{j}^{2}}{2} + y_{j}^{2} + \begin{array}{c} X & \frac{1}{jr_{j}} & \frac{r_{j}}{r_{j}} \end{array}$$

$$j = \begin{array}{c} \frac{r}{r} & \frac{r}{r} & \frac{1}{r_{j}} & \frac{r}{r} \end{array}$$
(32)

Here lengths have been rescaled in units of r_0 whereas times has been rescaled in units of $\overline{2}$ = . Furtherm ore, comparing (31) and (32), the dimensional are the one-dimensional vs two-dimensional coordinates and the additional term due to the con ming potential in (32).

As a result the exchange constants take the form

$$J_1 = J_1 \exp((\frac{p}{1} r));$$
 (33)

where J_1 is the nearest-neighbor exchange constant, J_2 is the next-nearest neighbor exchange constant, and J_1 for 1 3 is the exchange constant corresponding to the lparticle ring exchange. The exponents $_1$ are obtained by m in in izing the dimensionless action $_{2D}$ [fr_j()] for a given exchange process. Whereas in the strictly one-dimensional case was just a number, now the electron conguration changes as a function of density and, therefore, the exponents $_1$ depend on density, too.

Note that while in the one-dimensional case the inclusion of spectators had little e ect on the results, here the spectators turn out to be much more important §3]. Figure 6(a) shows the change of the exponents $_1$ as spectators are included. As one can see, the rst few spectators modify the results signi cantly. However, the results converge rapidly as more and more spectators are added. Thus, the spin couplings are generated by processes that involve the motion of a small number of close-by electrons. Therefore, these couplings should not be a ected by deviations from the perfect crystalline order at large distances, caused by quantum uctuations.

Figure 6(b) shows the exponents $_1$ as a function of the dimensionless density [53, 55]. Ring exchanges with more than four particles are not included as they are negligibly small at all densities. At small .12, the crystal geometry is still close to one-dimensional. In that regime $_1$ is the smallest exponent and therefore, as expected, the nearest-neighbor exchange J_1 dominates. However, as density increases and the distances between nearest neighbors and next-nearest neighbors become comparable, in the regime 12. .15 the three-particle ring exchange constant J_3 becomes largest. Finally, at even higher densities & 15 the four-particle ring exchange is dominant (until the zigzag crystal gives way to structures with more than two rows at 1:75). In the next section the ground states generated by these spin couplings willbe discussed.

4.2. Spin phases of the zigzag W igner crystal

In order to extract the spin properties of the ground state, it is convenient to rewrite H am iltonian (30) in terms of spin operators using the identity $P_{ik} = \frac{1}{2} + 2S_i$ §. In



F igure 6. (a) D ependence of the exponents $_1$ on the number of spectators included in the calculation [54]. Results are shown for = 1.3. (b) Exponents $_1$ for the nearest neighbor, next-nearest neighbor, three-particle ring, and four-particle ring exchange as a function of dimensionless density [55].

the absence of ring exchanges the system is described as a Heisenberg spin chain with nearest neighbor and next-nearest neighbor coupling,

$$H_{12} = (J_1 S_1 \underline{S}_1 + J_2 S_1 \underline{S}_2):$$
(34)

As discussed at the beginning of this section, depending on the ratio of J_1 and J_2 , one

nds an antiferrom agnetic and a dim er phase. The contribution of the three-particle ring exchange is

$$H_{3} = J_{3} (2S_{1} \not S_{1} + S_{1} \not S_{2}):$$
(35)

Thus, no new terms are generated the Ham iltonian retains the same form (34), albeit with modi ed coupling constants

$$\mathfrak{F}_1 = J_1 \quad 2J_3; \qquad \mathfrak{F}_2 = J_2 \quad J_3:$$
 (36)

The important consequence is that the new coupling constants \mathcal{F}_1 and \mathcal{F}_2 may now be either positive or negative, corresponding to antiferrom agnetic or ferrom agnetic interactions, respectively. The phase diagram of a Heisenberg spin chain with both antiferrom agnetic and ferrom agnetic nearest and next-nearest neighbor couplings has been widely studied in the literature [40, 41, 42, 43, 44, 56, 57, 58, 59, 60, 61]. In addition to the antiferrom agnetic and dimer phases existing for positive couplings, a ferrom agnetic phase appears. The phase diagram is shown in Figure 7 (a).

This phase diagram is su cient to determ ine the ground state of the stronglyinteracting zigzag W igner crystal at low and intermediate densities. At low densities, the system is in the antiferrom agnetic phase $(\mathfrak{F}_1 > 0, \mathfrak{F}_2 \mathfrak{j} = \mathfrak{F}_1)$. At intermediate densities, the three particle ring exchange dominates. As a result both coupling constants become negative, $\mathfrak{F}_1; \mathfrak{F}_2 < 0$, and therefore the system is in the ferrom agnetic



F igure 7. (a) Phase diagram of the Heisenberg spin chain with nearest neighbor coupling \mathcal{F}_1 and next-nearest neighbor coupling \mathcal{F}_2 . (b) P reliminary phase diagram of the zigzag spin chain including four-particle ring exchange J_4 , obtained by exact numerical diagonalization of nite-size chains [55]. When J_4 is large, novel phases appear. (Triangles, squares, and circles correspond to the boundaries obtained for N = 16, 20, and 24 sites, respectively.)

phase. The spontaneous spin polarization suggested as a possible explanation of the 0.7 anom aly can, thus, occur in strongly interacting quantum wires, if deviations from one-dimensionality are taken into account.

At higher densities, the situation becomes more complicated. W hile the threeparticle ring exchange only modiles the nearest neighbor and next-nearest neighbor exchange constants, the four-particle ring exchange generates new terms in the Hamiltonian, namely a next-next-nearest neighbor exchange and, more importantly, four-spin couplings. The corresponding spin Hamiltonian reads

$$H_{4} = J_{4} \sum_{\substack{n=1\\ n=1}}^{X} \frac{X^{3}}{2} \frac{4}{5} \frac{n}{2} S_{1} \sum_{\substack{n=1\\ n=1}}^{N} S_{1}$$

The phase diagram in the presence of these couplings is not yet fully understood. First results were obtained using exact diagonalization of short chains with up to N = 24 spins [55]. If $J_4 = j\mathcal{F}_1 j; j\mathcal{F}_2 j$ the same phases as in the Heisenberg spin chain without four-particle ring exchange appear as can be seen in Figure 7 (b). However, as J_4 becomes of the same order as the other coupling constants new phases appear. The simplest one to identify is a partially polarized phase (labeled M ' in Figure 7 (b)) adjacent to the ferrom agnetic phase. While this phase seem s to persist in size and shape as the num ber of spins increases, it is currently unclear whether it survives in the therm odynam ic lim it. In addition a region (labeled MP' in Figure 7 (b)) where the ground state is unpolarized but di erent from the antiferrom agnetic and dimer phases occurs. This 4P' region could



F igure 8. Spin ground states of interacting electrons in quantum wires in the zigzag regim e [55].

correspond to a single or several phases. Unfortunately, the size dependence in this part of the phase diagram turns out to be very complicated. Due to frustration introduced by the four-particle exchange, a large number of low energy states exist. Therefore, the study of short chains does not allow one to determ ine the properties of the ground state in this regim e.

4.3. Spin phases of interacting quantum wires in the quasi-one-dimensional regime

W hile the above results were obtained in the limit r 1, interaction parameters in realistic quantum wires vary widely, ranging from r < 1 in cleaved-edge overgrow th wires to r 20 in p-type gate-de ned wires 62, 63, 64]. W hile the form er are weakly interacting, the latter are clearly in the strongly interacting regime. However, the above analysis based solely on exponents is not su cient to determ ine the ground state of interacting electrons in a quantum wire at niter. In order to obtain a phase diagram in that case, the prefactors J_1 have to be computed which can be done by including G aussian uctuations around the classical exchange paths.

U sing the exchange constants $J_1(;r)$ computed in this way [55] and the phase diagram shown in Figure 7, the ground states realized for given system parameters can be determined. The resulting phase diagram is shown in Figure 8. It turns out that the partially and fully polarized phases are realized only at large r & 50. At moderately large r the transition occurs directly from the antiferrom agnetic phase to a phase dominated by the four-particle ring exchange. These notings, thus, do not support the interpretation [12, 13, 14, 15, 16, 17, 18, 20, 21, 22, 23, 24, 25] of the so-called 0.7 anom aly in terms of spontaneous spin polarization.

Even at su ciently strong interactions, the question arises of how a ferrom agnetic state in the quantum wire manifests itself in the conductance. It is tempting to assume that in the fully polarized state the wire supports only one excitation mode and thus



Figure 9. Simple model of exchange coupling in a ferrom agnetic W igner crystal coupled to non-magnetic leads. The coupling constant vanishes in the contact region at points a and a, and therefore the spin excitations in the leads and in the wire decouple.

has conductance $e^2=h$. This is indeed the case when the full polarization of electron spins is achieved by applying a su ciently strong magnetic eld. Such a eld creates a gap in the spectrum of spin excitations, and below the gap the system is equivalent to a spinless electron liquid with conductance $e^2=h$. It is important to stress that the situation is very dierent if the full spin polarization is achieved due to internal exchange processes in the electron system, rather than the external magnetic eld. In this case, the ground state is degenerate with respect to spin rotations, and thus the system supports gapless spin excitations is the magnons. As a result, the conventional argument in favor of conductance value $e^2=h$ no longer applies.

In studying the conductance of a ferrom agnetic wire it is important to keep in mind that the properties of the electron system inside the quantum wire in general do not fully determine its conductance. Indeed, since the electric current ows between non-magnetic leads through a ferrom agnetic wire, the spatial non-uniformity of the system needs to be considered carefully, and the problem of determining the conductance complicates considerably. In the case of a ferrom agnetic zigzag W igner crystal in the middle of the wire, the weakening of the continuity of a crystal in the contact region would lead to either melting of the crystal or the emergence of a crystal with more and more rows. In both cases modeling of the spin interactions in the transition region is by no means obvious.

The sim plest m odel that m ight capture the relevant physics is one where the system is described by H am iltonian (4) with an elective position-dependent nearest-neighbor exchange constant J (x) as depicted in Figure 9. In the leads, interactions are weak and antiferrom agnetic and therefore J is large and positive. In the wire, interactions are strong and ferrom agnetic and therefore J is small and negative. Through the contact regions, J varies smoothly and changes sign at points a and a. Within this model, the argum ents of section 2.3 lead to the conclusion that the spin polarization does suppress the conductance. N am ely, since the exchange coupling constant vanishes at the borders of the ferrom agnetic region, i.e., at a, the spin degrees of freedom in the leads are decoupled from those in the wire and, thus, the propagation of spin excitations through the wire is blocked. A coordingly, the value of the conductance is reduced by a factor 2. By contrast to the antiferrom agnetic case in one-dimensional wires, this suppression would persist down to temperatures T ! 0 due to the vanishing of the spin coupling in the contact region.

Of course the contact region in real quantum wires is more complex and a satisfactory theory for the conductance of strongly interacting quasi-one-dimensional quantum wires that correctly takes into account the spin degrees of freedom is an open problem.

5.0 rbital properties of zigzag W igner crystals

In addition to the spin physics discussed in the previous section, quasi-one-dimensional wires have interesting orbital properties. In this section, we discuss the transition from a one-dimensional to a quasi-one-dimensional state for the case of spinless electrons, based mainly on Ref. [65].

As shown in section 3, the classical transition from a one-dimensional to a zigzag W igner crystal can be obtained simply by minimizing the energy of the interacting electron system in a transverse con ming potential. A dimensional to a zigzag transition is by considering the phonon modes of the crystal. In the one-dimensional crystal one bogitudinal and one transverse phonon mode exist. The longitudinal phonon is gapless because sliding of the entire crystal along the wire axis does not cost any energy. On the other hand, the transverse mode is gapped with a gap frequency equal to the frequency of the conming potential. The transition to a zigzag state is driven by a softening of the transverse phonon at wave vector k = n which corresponds to a staggered displacement of electrons transverse to the wire axis. In the zigzag crystal, we obtain two longitudinal and two transverse phonon modes with the following low-q dispersions [66] close to the transition (= 1):

$$!_{k0} (q) = \frac{1}{2} \qquad {}_{c}^{3} \ln \frac{1}{\dot{q}\dot{q}} \dot{q}\dot{q}; \qquad !_{k} (q) = {}^{p} \frac{1}{2} + O(q^{2}); \qquad (38)$$

$$!_{?0}(q) = + O(q^{2}); \quad !_{?}(q) = {}^{p} \frac{-}{6} - \frac{{}^{2} \ln 2}{-}_{c} + \frac{{}^{2} \ln 2}{48} {}^{3}_{c} q^{2}; \quad (39)$$

where q = k = (n).

Thus, only at the transition point p = 0, two gapless phonon modes exist with dispersions $!_{k0}$ (q) and $!_{?}$ (q) = (=2, 2) $p = \frac{0}{c^{3} \ln 2}$ jqj. W ithin the zigzag regime, there is a single gapless excitation corresponding to in-phase longitudinal motion of the two rows that constitute the zigzag crystal. The soft-mode $!_{?}$ (q) describing the out-of-phase transverse motion acquires a gap c_{l} /

This behavior is markedly di erent from the noninteracting case. In a noninteracting system the transition from a one-dimensional to a quasi-one-dimensional state happens when the chemical potential is raised above the subband energy of the second subband of transverse quantization. In the quasi-one-dimensional state, the two occupied subbands are decoupled and each of them supports a gapless electronic



F igure 10. At zero and in nite interaction strength the quasi-one-dimensional system supports two and one gapless excitation mode, respectively. Here the interaction strength is characterized by the parameter r introduced in Sec. 3. Possible phase diagram s consistent with these ndings are shown: (a) A tricritical point exists at a nite interaction strength. (b) W eak quantum uctuations destroy the gap of the classical W igner crystal. (c) A lready in nitesimally weak interactions induce a gap in the second mode.

excitation mode, i.e., above the transition two gapless modes exist rather than just one as in the classical W igner crystal.

One might, thus, expect that the phase diagram of the system as a function of interaction strength is as shown in Figure 10(a), namely two distinct quasi-onedimensional phases exist at weak and strong interactions. Consequently one should

nd a tricritical point at a nite interaction strength where the nature of the transition from a one-dimensional to a quasi-one-dimensional state changes. However, the phase diagram Figure 10 (a) is not the only one consistent with both the above notings for the noninteracting case and the classical W igner crystal at in nite interaction strength. Two alternatives are shown in Figure 10 (b,c). To distinguish between the di erent possibilities, one needs to study the nature of the transition as a function of interaction strength. In particular, the following questions have to be answered: (i) Do weak quantum uctuations destroy the gap found in the classical zigzag crystal at strong interactions? (ii) Do in nitesim ally weak interactions lead to a gap in the second mode above the transition?

5.1. Quantum theory of the zigzag transition

Let us consider the strongly interacting case rst and account for the quantum nature of the system. In particular, using the classical W igner crystal con guration as a starting point, we now include quantum uctuations. The phonon modes \$8) and (39) re ect the fact that there are only two types of possible low energy excitations: the longitudinal plasm on mode and a staggered transverse mode. It turns out that in the vicinity of the transition the two modes decouple. The acoustic spectrum of the plasm on mode is protected by translational invariance and, thus, at least one gapless excitation mode exists in the system. M ore interesting is the staggered transverse mode.



Figure 11. M apping of the $'^4$ -theory to a spin chain.

To describe the transverse displacements of the electrons, a staggered eld $'_1 = (1)^3 y_1$ is introduced. In the vicinity of the transition, $'_1$ is slow by varying on the scale of the inter-electron distances and, therefore, the continuum limit $'_1$! '(x) can be taken. Expanding the action up to fourth order in ', one nds

$$S['] = A \sim \frac{p_{r}}{r} d dx (@')^{2} + (@_{x'})^{2} + ("_{x'})^{2}$$
 (40)

where the variables have been rescaled such as to provide the simplest action possible. The form of the action as well as all following conclusions do not depend on the exact shape of the con ning potential. For a parabolic con ning potential the constant A is given as $A = [7 (3)]^{3-2}$ $\overline{h2} = (31 (5))$.

The classical transition point as discussed above corresponds to = 0. Here the transverse mode becomes unstable, and the quartic term is needed to stabilize the uctuations may a ect both the transition point and the nature of system. Quantum the transition. A convenient way to analyze the quantum -m echanical problem is to referm ionize. As a rst step, we rediscretize the coordinate x along the wire axis. The discrete version of the H am iltonian then describes a set of particles m oving in a double- $\frac{2}{1}$ + $\frac{4}{1}$ (as depicted in Figure 11) and interacting through a well potential V_{DW} nearest-neighbor interaction / (' $_{j}$ ' $_{j+1}$)². If the double-well potential is su ciently deep, i.e., if is su ciently large, the particles are almost completely localized in one of the wells at $'_j = p - \frac{1}{2}$. Then each particle can be described by a pseudo-spin operator, namely $'_j = p - \frac{1}{2} \frac{z}{j}$, where z_j^z is a Pauli matrix. In terms of these new variables, the H am iltonian consists of two terms corresponding to tunneling between the two wells and the nearest-neighbor interaction, respectively. Junneling is described by $H_t = t_j x_j$ whereas the interaction term reads $H_{NN} = v_j x_j^2 x_{j+1}$. The resulting Ham iltonian $H_t + H_{NN}$ is the Ham iltonian of the transverse eld Ising model [67]. Here the param eters t and v are related to the param eters of the originalm odel. In particular, they can be tuned by changing the chem ical potential which controls the transition, i.e., t = t() and v = v().

In order to arrive at a ferm ionic description, a Jordan-W igner transformation is used. It turns out that the Ham iltonian takes a much simpler form if one rotates *! ^z rst. The representation of the spin operators in terms of (spinless) ferm ions,

 $\begin{array}{c} \stackrel{*}{_{j}} \quad \stackrel{x}{_{j}} + i \stackrel{y}{_{j}} = 2a_{j}^{y}e^{i\sum_{i< j}a_{1}^{y}a_{i}}; \quad j \quad \stackrel{x}{_{j}} \quad i \stackrel{y}{_{j}} = 2e^{i\sum_{i< j}a_{1}^{y}a_{i}}a_{j}; \quad \stackrel{z}{_{j}} = 2a_{j}^{y}a_{j} \quad 1; (41) \\ \text{where } a_{j}^{y} \text{ and } a_{j} \text{ are ferm ion creation and annihilation operators on site } j, \text{ respectively,} \end{array}$



F igure 12. A first the Jordan-W igner transform ation, one obtains a tight binding model for spinless ferm ions with bandwidth 2v and chemical potential 2t. The transition from a one-dimensional to a quasi-one-dimensional state happens when the chemical potential reaches the bottom of the band.

then yields the noninteracting H am iltonian [67]

$$H_{f} = \begin{array}{c} X & h & i \\ H_{f} = & 2ta_{j}^{Y}a_{j} & v a_{j}^{Y} & a_{j} & a_{j+1}^{Y} + a_{j+1} \end{array}$$
(42)

Note that this Hamiltonian is essentially the transfer matrix of the two-dimensional classical Ising model [68] near the transition. The connection can be made clear by considering the mapping between d-dimensional quantum and (d + 1)-dimensional classical models [69]. Thus, the one-dimensional quantum Ising model studied here is equivalent to the two-dimensional classical Ising model [70].

In Hamiltonian (42) one can identify three di erent contributions: $v(\check{a}_{ja_{j+1}} + a_{j+1}^{Y}a_{j})$ describes a tight-binding model with bandwidth 4v, the local term $2ta_{ja_{j}}^{Y}a_{j}$ yields the chemical potential f = 2t of the spinless fermions, and nally $v\check{a}_{j+1}^{Y} a_{ja_{j+1}}$) is a BCS-like pairing term with p-wave symmetry. The one-dimensional regime of our original model corresponds to t > v when the chemical potential lies below the bottom of the tight-binding band and, therefore, all the fermionic states are empty. The transition to a quasi-one-dimensional regime happens when the chemical potential reaches the bottom of the band at t = v. For t < v, some of the fermionic states describing the motion of the original electrons transverse to the wire axis are lied. Due to the pairing term in the Hamiltonian, these states acquire a gap. W ith the help of a Bogoliubov transform ation, the Hamiltonian can be diagonalized to obtain the energy spectrum. As a result one motion of the term is given as = 2t, vj.

In term softhe original system parameters, one expects that t and v are non-singular functions of the chemical potential. The critical chemical potential $_{\rm c}$ is thus de ned by the condition t($_{\rm c}$) = v($_{\rm c}$). Furthermore, the behavior of the gap is obtained by expanding t $_{\rm c}$ in the vicinity of the transition point $_{\rm c}$. As a consequence one obtains a linear gap,

W hile quantum e ects modify the nature of the transition, the number of gapless

excitations remains the same: in the strongly interacting system, only one gapless excitation exists. Thus, the phase diagram of Figure 10 (b) is ruled out | weak quantum

uctuations do not destroy the gap of the transverse m ode in the quasi-one-dimensional regime. To dimensional between the phase diagrams of Figures 10(a) and 10(c), a complementary approach has to be used. In the next section we consider the limit of weak interactions to check whether or not they lead to the form ation of a gap just above the transition, as suggested by the scenario of Figure 10(c).

5.2. Two-subband system at weak interactions

The lim it of weak interactions can be treated using a renorm alization group approach. Here the description in terms of two subbands due to transverse size quantization is a good starting point. Each subband is described by ferm ionic operators j, where j = 1;2. The free Ham iltonian is just

$$H_{0} = \int_{j}^{X} dx \frac{2}{2m} \int_{j}^{y} (\theta^{2} + \eta_{j}) \int_{j}^{y} (\theta$$

where "j are the subband energies. For a parabolic con ning potential, "j = - (j $\frac{1}{2}$).

Interactions can be separated into intra-subband and inter-subband interactions. One needs four interaction constants to describe the system: $g_j = V_{jj}(0) = V_{jj}(2k_{Fj})$ which describes intra-subband forward scattering,

$$g_x = V_{12}(0) = \frac{1}{2} (V_{12}^{ex} (k_{F1} = k_{F2}) + V_{12}^{ex} (k_{F1} + k_{F2}))$$
 (45)

which describes inter-subband forward scattering, and

$$g_t = V_{12}^{ex} (k_{F1} = k_{F2}) = V_{12}^{ex} (k_{F1} + k_{F2})$$
 (46)

which describes transfer of two particles between the subbands as shown in Figure 13(a). Here \mathbf{z}

$$V_{ij}(k) = \frac{dx dx^{0} e^{ik(xx^{0})}}{Z} dy dy^{0} V_{int}(r r^{0}) \frac{2}{i}(y) \frac{2}{j}(y^{0});$$
(47)

$$V_{ij}^{ex}(k) = dx dx^{0} e^{ik(x x^{0})} dy dy^{0} V_{int}(r r^{0})_{i}(y)_{j}(y)_{i}(y^{0})_{j}(y^{0}); (48)$$

where $_{i}$ are the transverse eigenmodes in the con ning potential.

It is well known that forward scattering in one dimension does not open a gap in the system [7]. By contrast, the two-particle transfer between subbands described by the coupling constant g_t could open a gap. To assess whether this is indeed the case, the renormalization group (RG) is used, i.e., reducing the bandwidth from D₀ down to D, the scale-dependent coupling constants are determined. The RG equations for a two-band system are given as [71, 72, 73]

$$g_{1}^{0} = \frac{1}{2 - v_{F_{2}}} g_{t}^{2}; \qquad g_{2}^{0} = \frac{1}{2 - v_{F_{1}}} g_{t}^{2}; \qquad g_{x}^{0} = \frac{1}{- (v_{F_{1}} + v_{F_{2}})} g_{t}^{2}; \quad (49)$$

$$g_{t}^{0} = \frac{1}{2 \sim} \frac{g_{1}}{v_{F1}} + \frac{g_{2}}{v_{F2}} - \frac{4g_{x}}{v_{F1} + v_{F2}} \quad g_{t};$$
(50)



Figure 13. (a) Two-particle transfer between subbands described by the coupling constant g_t . (b) W eak coupling RG ow.

s ____

where the derivatives are taken with respect to $= \ln (D_0=D)$. By introducing the dimensionless coupling constants

$$y = \frac{1}{2 \sim} \frac{g_1}{v_{F1}} + \frac{g_2}{v_{F2}} - \frac{4g_x}{v_{F1} + v_{F2}} ; \qquad y_t = \frac{g_t}{\sim} - \frac{(v_{F1} + v_{F2})^2 + 4v_{F1}v_{F2}}{2v_{F1}v_{F2}(v_{F1} + v_{F2})^2}; \qquad (51)$$

the four RG equations can be combined into two equations [73]

$$y^{0} = y_{t}^{2};$$
 $y_{t}^{0} = yy_{t};$ (52)

The ow diagram corresponding to these equations is shown in Figure 13 (b).

The coupling constant g_t describes a combination of two processes: the particles transferred between subbands may retain their direction of motion, corresponding to momentum transfer $(k_{F1} + k_{F2})$, or they may change their direction of motion, corresponding to momentum transfer $(k_{F1} + k_{F2})$. Both processes are depicted in F igure 13 (a). The resulting coupling constant, thus, is proportional to $V_{12}^{ex}(k_{F1} + k_{F2})$ as given in equation (46). Consequently, $g_t^{(0)} / k_{F2}$ as the density in the second subband goes to zero, and one concludes that $y_t^{(0)} / \frac{p}{v_{F2}}$ is much smaller that $y^{(0)}$. Therefore the presence or absence of a gap just above the transition to a quasi-one-dimensional state is determined by the sign of $y^{(0)}$. If $y^{(0)} < 0$, the coupling constant y_t ow s to zero, and the system remains gapless. On the other hand, if $y^{(0)} > 0$, the coupling constant y_t ow s to in nity, and the system acquires a gap.

The interaction constant $y^{(0)}$ can be evaluated assuming a Coulomb interaction screened by a gate at a distance d much larger than the e ective width of the wire, i.e.,

$$V_{int}(\mathbf{r}) = \frac{e^2}{2} \frac{1}{r} \frac{p}{r^2 + (2d)^2}$$
 (53)

which is the two-dimensional version of Eq. (1).

One nds that $q = 2 (e^2 =) \ln k_{\rm F1} d$ (with logarithm ic accuracy). On the other hand, at densities $n_2 = 1=d$,

$$g_2 = \frac{e^2}{k_{\rm F2}} (k_{\rm F2})^2 \ln \frac{1}{k_{\rm F2}};$$
 (54)



F igure 14. Phase diagram of spinless interacting electrons in a quantum wire [65]. At any interaction strength there is a nite window of densities where the quasi-onedimensional system supports only one gapless excitation.

i.e., the interaction constant g_2 vanishes in the lim it $n_2 ! 0$. This is a manifestation of the Pauli exclusion principle: Once the average distance between particles exceeds the distance to the gate, the interactions become e ectively local. However, identical ferm ions do not interact via a local interaction, hence $g_2 ! 0$.

A second gapless excitation m ode appears only once the density is increased further beyond the transition point. As the density increases, $g_2=v_{F2}$ increases and becomes comparable to $g_1=v_{F1}$. Then $y^{(0)}$ changes sign and eventually one crosses into the regime where y_t scales to zero. At weak interactions this happens at k_{F2} $1=(k_{F1}d^2)$. Thus, at any interaction strength there is a nite window of densities in which the system is in the quasi-one-dimensional state but supports only one gapless excitation mode. The resulting phase diagram [65] is shown in Figure 14.

Having found that the behavior at weak and strong interactions is very similar, there is no reason to expect that at interm ediate interactions no gap exists. One notices, how ever, that the magnitude of the gap strongly depends on interaction strength. In the W igner crystal we nd a large Ising gap j j. At weak interactions, on the other hand, the gap scales with a large exponent, (), where $= 1 = (4y^{(0)})$.

5.3. Interm ediate interactions

The method of choice to treat intermediate interactions in one-dimensional and quasione-dimensional systems is bosonization. However, bosonization requires a linear spectrum. In the present case this is not straightforward because, to describe the transition, one is necessarily interested in what happens at the bottom of the second subband where a linearization is not justimed.

A lternatively one may bosonize the subband which has a large Ferm i energy and keep a ferm ionic description in the second subband [74]. Thus, the electrons in the

rst subband are described by the bosonic $elds_1(x)$ and $_1(x)$ whereas the electrons in the second subband are described by the ferm ionic creation and annihilation operators,

 $\frac{y}{2}$ (x) and $_{2}$ (x). In particular,

$$H = \frac{-v_{F_1}}{2} dx \quad (@_1)^2 + \frac{1}{K^2} (@_1)^2 \quad \frac{-2}{2m} dx \quad \frac{v_2}{2} @_2^2 \qquad \frac{1}{2} \frac{1}{m} dx \quad \frac{v_2}{2} @_2^2 \qquad \frac{v_2}{2} @_2^2 \qquad \frac{1}{m} dx \quad \frac{v_2}{2} @_2^2 \qquad \frac{v_2}{2} @_2$$

where $_t$ $\stackrel{2}{e}=$. Furtherm ore, K = $(1+q=~ \sim v_{F\,1})^{1=2}$ is the Luttinger parameter in the rst subband.

The dom inant interaction between the bosons and the ferm ions is the intersubband forward scattering V_{12} . This coupling can be elim inated by applying a unitary transformation

$$U = \exp - \frac{iK^2}{\sim V_{F1}} dx dy_1(x) V(x y) n_2(y) :$$
 (56)

The new H am iltonian in term s of the transform ed bosonic ($_{c}$; $_{c}$) and ferm ionic ($_{s}^{y}$; $_{s}$) elds then reads

$$H_{U} = U H U^{Y} = \frac{\sim v_{F1}}{2} \int_{X}^{Z} dx \quad (@_{c})^{2} + \frac{1}{K^{2}} (@_{c})^{2} \qquad \frac{\sim^{2}}{2m} \int_{x}^{Z} dx \quad \int_{s}^{y} @_{s}^{2} \\ + \int_{t}^{z} dx \quad (\int_{s}^{y} @_{s}^{Y} & @_{s}^{Y} g) e^{2i} \quad c^{(x)} + hc;; \qquad (57)$$

i.e., the inter-subband forward scattering disappears. C om paring the H am iltonians (55) and (57), note that the exponent in the boson-ferm ion interaction term changes from 2i_c to 2i_c, where = 1 $K^2g_x=(~v_{F1})'K^2$. It is essential to realize that other than that the H am iltonian preserves its form after the unitary transform ation. N am ely we are still dealing with a plasm on m ode coupled to noninteracting ferm ions. N ot only the bare interaction in the second subband, but also the e ective interaction generated by the inter-subband forward scattering vanishes in the lim it n_2 ! 0. A dditional term s that are generated by the unitary transform ation can be shown to be irrelevant [74].

Since the ferm ions remain noninteracting, as a next step, they can be bosonized. The purely bosonic Ham iltonian could then in principle be subject to an RG approach. Or, as it is safe to assume that at intermediate interactions the second mode is still gapped, one may use a variational approach instead. One nds that the gap exponent



F igure 15. (a) Tunneling into a zigzag crystal. (b) In addition to exciting the plasm on mode, the tunneling electron creates a defect. The nite energy cost associated with the process manifests itself in a gap in the tunneling density of states.

decreases with increasing interaction strength until the variational approach is no longer valid because the relevant energy scale exceeds the Ferm i energy in the second subband [66]. For stronger interactions, note that the Ham iltonian (57) in the limit K ! O takes the same form as the Ham iltonian of the W igner crystal with a gapless plasm on m ode decoupled from the gapped Ising ferm ions.

5.4. Experim entally observable consequences

As mentioned earlier the computation of observables such as the conductance is complicated due to the importance of the coupling to leads. O nem ay speculate, how ever, how the above ndings a ect observables.

The experim entally most relevant observable is the conductance. For noninteracting electrons, the second subband opens a new channel in the wire and, therefore, at the transition the conductance doubles from $G = e^2 = h$ to $G = 2e^2 = h$ (for spinless electrons). In the interacting case, however, the second mode is gapped. One might argue [76] that the total charge mode (plasm on) remains gapless and, therefore, one should still expect a doubling of the conductance at the transition. However, as discussed in section 2, the conductance is not determ ined by the total charge m ode only. As the wire is coupled to leads, mixing between di erent channels occurs and, therefore, modes other than the total charge mode do a ect the conductance. We expect that in this case, too, the fact that the second mode is gapped leads to a suppression of the conductance which should rem ain at its one-dimensional value of $G = e^2$ -h until the second mode becomes gapless at a higher density. This means that the transition from a one-dimensional state to a quasi-one-dimensional state and the step in conductance no longer coincide. Only at higher tem peratures T >does the gapped mode open for transport. Thus, the presence of a gapped mode is expected to lead to non-trivial temperature dependence of the conductance.

The gapped mode above the transition should manifest itself most clearly in the tunneling density of states. Consider the W igner crystal limit. In the one-dimensional case, the addition of an electron to the system requires the excitation of the plasmon

[{] A more careful treatment [75] shows that at strong interactions the weak coupling of the two modes is marginally irrelevant and leads to relatively insigni cant corrections to the Ising picture of the transition.

m ode in order to adjust the density along the wire. Due to the sti ness of the plasm on m ode, the tunneling density of states is suppressed: As discussed in section 2.1 the W igner crystal described as an elastic m edium can be viewed as a Luttinger liquid, and the tunneling density of states of a Luttinger liquid is well known to display a powerlaw suppression at the Ferm i level [77, 78]. In the zigzag crystal, the addition of an electron to the system also requires to adjust the density along the wire by exciting plasm ons which suggests a power-law suppression of the density of states. A part from that, however, the addition of an electron creates a defect in the zigzag structure: the electron is added to one of the two rows and, thus, interrupts the zigzag pattern as depicted in Figure 15. The energy of such a defect is nite, and, therefore, the density of states acquires a gap.

This behavior is not limited to the W igner crystal. As discussed in Ref. [76], at any interaction strength tunneling of a single electron into the bulk of the w ire excites both the gapless and the gapped m ode,⁺ and the nite energy cost associated with excitation of the gapped m ode entails a gap in the tunneling density of states. Consequently the observation of a gap opening in the tunneling density of states would allow one to identify the transition to the quasi-one-dimensional state.

6. Conclusion

The Luttinger liquid physics of one-dimensional electron system swith weak to moderate interactions has been studied extensively. The present review focuses on novel phenomena due to strong interactions which lead to the formation of a W igner crystal [27]. The strongly interacting regime can be realized experimentally, and evidence for W igner crystal physics has been seen in the conductance of quantum wires [79, 80], the Coulomb blockade peaks in carbon nanotubes [81], and possibly [82, 83] in the localization features in double quantum wires [84, 85]. While no phase transition takes place, at stronger interactions the system properties change due to the presence of two very di erent energy scales, namely the Fermi energy E_F and the spin exchange energy J $E_{\rm F}$. In the strictly one-dimensional regime, one of the main features of Luttinger liquid physics is spin-charge separation [7]. In an inhom ogeneous W igner-crystal wire, however, spin physics is found to a ect the conductance, reducing it from 2e²=h at T J to $e^2 = h$ in the tem perature regime J Т E_{F} as discussed in Sec.2.

Real systems are never strictly one-dimensional, but con ned by an external potential. The presence of transverse degrees of freedom leads to a transition from a one-

⁺ W ithin the formulation presented here, this can be understood by going back to the unitary transformation (56) which relates the original degrees of freedom described by Hamiltonian (55) to the new degrees of freedom described by Hamiltonian (57). In particular, applying the unitary transformation to the single electron creation operators $\frac{y}{j}$, where j = 1;2 is the subband index, one may verify that $\frac{y}{1}$ as well as $\frac{y}{2}$ contain contributions from both the gapless and the gapped mode of (57).

dimensional to a zigzag W igner crystal at a nite electron density, see Sec.3. In contrast to the one-dimensional crystal, the zigzag W igner crystal displays a variety of spin ground states as a function of density, see Sec. 4. In particular, a ferrom agnetic ground state which has been suggested as a possible cause of the conductance anom alies observed in quantum wires [12] can be realized. W hile for noninteracting electrons the transition to a quasi-one-dimensional state entails the emergence of a second gapless excitation mode, this is not the case in the presence of interactions. As discussed in Sec. 5, the orbital degrees of freedom are strongly a ected by interactions which, for example, are expected to lead to a gap in the tunneling density of states. The most interesting properties of the quasi-one-dimensional state in quantum wires are summarized in the phase diagram s Figure 8 (spin properties) and Figure 14 (orbital properties).

Figure 8 shows the spin phases of the zigzag W igner crystal obtained under the assumption that spin and orbital properties can be treated separately. This approach is justilled at strong interactions, when the energy scales for spin and charge excitations are very diment, $J = E_F$. However, as interactions become weaker the crystal starts to melt, leading to the coupling of spin and orbital degrees of freedom. To study the behavior of the system in this regime, one needs to develop a theory that treats spin and orbital degrees of freedom on equal footing. This entails a number of open questions: A re there remnants of the W igner crystal phase dominated by the four-particle ring exchange in the weakly interacting quasi-one-dimensional state? Is the spectral gap discussed in Sec. 5 robust to the inclusion of spin?

Figure 14 sum marizes the orbital properties of the electron system in a quantum wire near the transition from a one-dimensional to a quasi-one-dimensional state. The upper line indicates the vanishing of the gap in the second excitation mode. While the appearance of a second gapless excitation at a nite distance above the transition has been shown in the limit of weak interactions [65], more careful treatment is required to explore this phenomenon at nite interaction strength. In the opposite limit of strong interactions, with increasing electron density the zigzag regime eventually breaks down, giving way to structures with more than two rows. Numerical study of the quasi-one-dimensional W igner crystal [32] shows that the number of rows changes as $2 \mid 4 \mid 3 \mid 4 \mid 5 \dots$ as a function of density. Since in a wide channel the electron density is not uniform across the wire [86, 87], this trend cannot persist up to an arbitrarily high number of rows. Instead one expects that structures with defects will have a low erenergy. The presence of such potentially mobile defects will be crucial for understanding transport properties of quantum wires in that regime.

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